# **Quad 2-Input NAND Gate With Open-Drain Outputs**

# **High-Performance Silicon-Gate CMOS**

The MC74HC03A is identical in pinout to the LS03. The device inputs are compatible with Standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The HC03A NAND gate has, as its outputs, a high–performance MOS N–Channel transistor. This NAND gate can, therefore, with a suitable pullup resistor, be used in wired–AND applications. Having the output characteristic curves given in this data sheet, this device can be used as an LED driver or in any other application that only requires a sinking current.

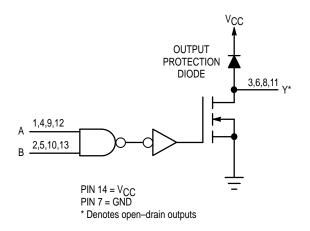
- Output Drive Capability: 10 LSTTL Loads With Suitable Pullup Resistor
- · Outputs Directly Interface to CMOS, NMOS and TTL
- High Noise Immunity Characteristic of CMOS Devices
- Operating Voltage Range: 2 to 6V
- Low Input Current: 1μA
- In Compliance With the JEDEC Standard No. 7A Requirements
- · Chip Complexity: 28 FETs or 7 Equivalent Gates

## **DESIGN GUIDE**

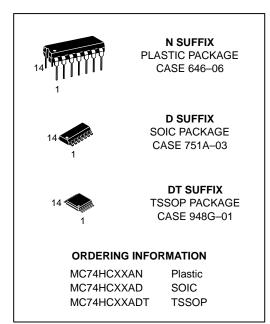
| Criteria                        | Value  | Unit |
|---------------------------------|--------|------|
| Internal Gate Count*            | 7.0    | ea   |
| Internal Gate Propagation Delay | 1.5    | ns   |
| Internal Gate Power Dissipation | 5.0    | μW   |
| Speed Power Product             | 0.0075 | pJ   |

<sup>\*</sup> Equivalent to a two-input NAND gate

# LOGIC DIAGRAM



# MC74HC03A

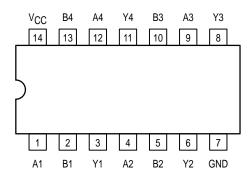


## **FUNCTION TABLE**

| Inputs |   | Output |
|--------|---|--------|
| Α      | В | Y      |
| L      | L | Z      |
| L      | Н | Z      |
| Н      | L | Z      |
| Н      | Н | L      |

Z = High Impedance

# Pinout: 14-Lead Packages (Top View)



# **MAXIMUM RATINGS\***

| Symbol           | Parameter   | Value                         | Unit |
|------------------|---|-------------------------------|------|
| VCC              | DC Supply Voltage (Referenced to GND)   | - 0.5 to + 7.0                | V    |
| V <sub>in</sub>  | DC Input Voltage (Referenced to GND)  | $-0.5$ to $V_{CC} + 0.5$      | V    |
| V <sub>out</sub> | DC Output Voltage (Referenced to GND)   | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| lin              | DC Input Current, per Pin   | ± 20                          | mA   |
| l <sub>out</sub> | DC Output Current, per Pin  | ± 25                          | mA   |
| ICC              | DC Supply Current, V <sub>CC</sub> and GND Pins                                       | ± 50                          | mA   |
| PD               | Power Dissipation in Still Air Plastic DIP† SOIC Package† TSSOP Package†              | 750<br>500<br>450             | mW   |
| T <sub>stg</sub> | Storage Temperature   | - 65 to + 150                 | °C   |
| TL               | Lead Temperature, 1 mm from Case for 10 Seconds<br>Plastic DIP, SOIC or TSSOP Package | 260                           | °C   |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range GND  $\leq$  ( $V_{in}$  or  $V_{out}$ )  $\leq$  VCC. Unused inputs must always be tied to an appropriate logic voltage

level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

SOIC Package: - 7 mW/°C from 65° to 125°C

TSSOP Package: - 6.1 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

## RECOMMENDED OPERATING CONDITIONS

| Symbol                             | Parameter  |  |             | Max                | Unit |
|------------------------------------|--|--|-------------|--------------------|------|
| VCC                                | DC Supply Voltage (Referenced to GND)                |  |             | 6.0                | V    |
| V <sub>in</sub> , V <sub>out</sub> | DC Input Voltage, Output Voltage (Referenced to GND) |  |             | VCC                | V    |
| TA                                 | Operating Temperature, All Package Types             |  |             | + 125              | °C   |
| t <sub>r</sub> , t <sub>f</sub>    | Input Rise and Fall Time VC (Figure 1) VC VC         | CC = 2.0 V<br>CC = 4.5 V<br>CC = 6.0 V | 0<br>0<br>0 | 1000<br>500<br>400 | ns   |

# DC CHARACTERISTICS (Voltages Referenced to GND)

|                 |   |   | VCC                      | Guaranteed Limit             |                              |                              |      |
|-----------------|---|---|--------------------------|------------------------------|------------------------------|------------------------------|------|
| Symbol          | Parameter   | Condition   | V                        | –55 to 25°C                  | ≤85°C                        | ≤125°C                       | Unit |
| VIH             | Minimum High-Level Input Voltage                  | $V_{out} = 0.1V$ or $V_{CC} = -0.1V$<br>$ I_{out}  \le 20\mu A$   | 2.0<br>3.0<br>4.5<br>6.0 | 1.50<br>2.10<br>3.15<br>4.20 | 1.50<br>2.10<br>3.15<br>4.20 | 1.50<br>2.10<br>3.15<br>4.20 | V    |
| VIL             | Maximum Low-Level Input Voltage                   | $V_{out} = 0.1V$ or $V_{CC} - 0.1V$<br>$ I_{out}  \le 20\mu A$  | 2.0<br>3.0<br>4.5<br>6.0 | 0.50<br>0.90<br>1.35<br>1.80 | 0.50<br>0.90<br>1.35<br>1.80 | 0.50<br>0.90<br>1.35<br>1.80 | V    |
| VOL             | Maximum Low–Level Output<br>Voltage               | $V_{out} = 0.1V \text{ or } V_{CC} - 0.1V$<br>$ I_{out}  \le 20\mu\text{A}$   | 2.0<br>4.5<br>6.0        | 0.1<br>0.1<br>0.1            | 0.1<br>0.1<br>0.1            | 0.1<br>0.1<br>0.1            | V    |
|                 |   | $ \begin{aligned} V_{\text{in}} = V_{\text{IH}} \text{ or } V_{\text{IL}} & &  I_{\text{out}}  \leq 2.4 \text{mA} \\ &  I_{\text{out}}  \leq 4.0 \text{mA} \\ &  I_{\text{out}}  \leq 5.2 \text{mA} \end{aligned} $ | 3.0<br>4.5<br>6.0        | 0.26<br>0.26<br>0.26         | 0.33<br>0.33<br>0.33         | 0.40<br>0.40<br>0.40         |      |
| l <sub>in</sub> | Maximum Input Leakage Current                     | $V_{in} = V_{CC}$ or GND  | 6.0                      | ±0.1                         | ±1.0                         | ±1.0                         | μΑ   |
| lcc             | Maximum Quiescent Supply<br>Current (per Package) | $V_{in} = V_{CC}$ or GND<br>$I_{out} = 0\mu A$  | 6.0                      | 1.0                          | 10                           | 40                           | μΑ   |
| loz             | Maximum Three–State Leakage<br>Current            | Output in High–Impedance State  Vin = VIL or VIH  Vout = VCC or GND   | 6.0                      | ±0.5                         | ±5.0                         | ±10                          | μА   |

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

<sup>†</sup>Derating — Plastic DIP: - 10 mW/°C from 65° to 125°C

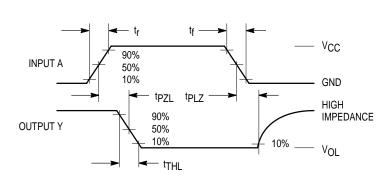
# **AC CHARACTERISTICS** ( $C_L = 50pF$ , Input $t_f = t_f = 6ns$ )

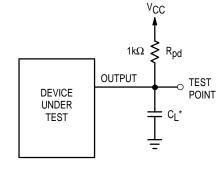
|  |   | ν <sub>CC</sub>          | Guaranteed Limit      |                       |                       |      |
|--|---|--------------------------|-----------------------|-----------------------|-----------------------|------|
| Symbol                                 | Parameter   | "V"                      | –55 to 25°C           | ≤85°C                 | ≤125°C                | Unit |
| tPLZ,<br>tPZL                          | Maximum Propagation Delay, Input A or B to Output Y (Figures 1 and 2) | 2.0<br>3.0<br>4.5<br>6.0 | 120<br>45<br>24<br>20 | 150<br>60<br>30<br>26 | 180<br>75<br>36<br>31 | ns   |
| t <sub>TLH</sub> ,<br>t <sub>THL</sub> | Maximum Output Transition Time, Any Output (Figures 1 and 2)          | 2.0<br>3.0<br>4.5<br>6.0 | 75<br>27<br>15<br>13  | 95<br>32<br>19<br>16  | 110<br>36<br>22<br>19 | ns   |
| C <sub>in</sub>                        | C <sub>in</sub> Maximum Input Capacitance                             |                          | 10                    | 10                    | 10                    | pF   |
| C <sub>out</sub>                       |   |                          | 10                    | 10                    | 10                    | pF   |

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

|                 |   | Typical @ 25°C, V <sub>CC</sub> = 5.0 V, V <sub>EE</sub> = 0 V |    |
|-----------------|---|--|----|
| C <sub>PD</sub> | Power Dissipation Capacitance (Per Buffer)* | 8.0  | pF |

<sup>\*</sup> Used to determine the no–load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup>f + I<sub>CC</sub> V<sub>CC</sub>. For load considerations, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

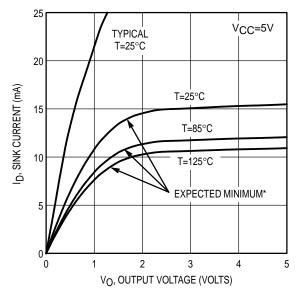




\*Includes all probe and jig capacitance

Figure 1. Switching Waveforms

Figure 2. Test Circuit



<sup>\*</sup>The expected minimum curves are not guarantees, but are design aids.

Figure 3. Open-Drain Output Characteristics

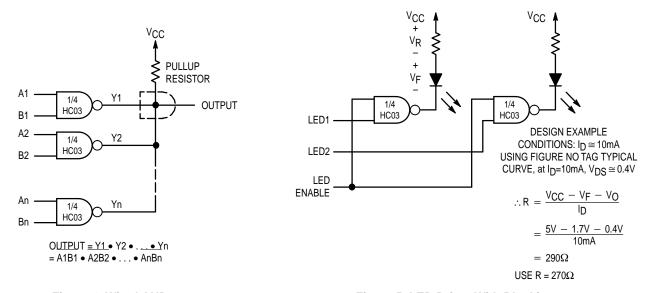


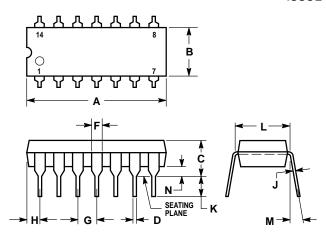
Figure 4. Wired AND

Figure 5. LED Driver With Blanking

# **OUTLINE DIMENSIONS**

# **N SUFFIX**

PLASTIC DIP PACKAGE CASE 646-06 ISSUE L



- NOTES:

  1. LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.

  2. DIMENSION L TO CENTER OF LEADS WHEN CONDITION PARALLE.
- FORMED PARALLEL.
  3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

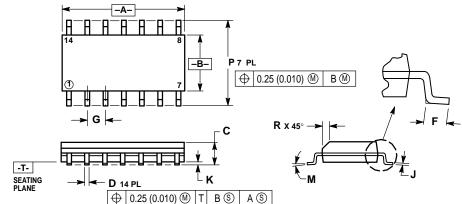
  4. ROUNDED CORNERS OPTIONAL.

|     | INC   | HES       | MILLIMETERS |       |  |
|-----|-------|-----------|-------------|-------|--|
| DIM | MIN   | MAX       | MIN         | MAX   |  |
| Α   | 0.715 | 0.770     | 18.16       | 19.56 |  |
| В   | 0.240 | 0.260     | 6.10        | 6.60  |  |
| С   | 0.145 | 0.185     | 3.69        | 4.69  |  |
| D   | 0.015 | 0.021     | 0.38        | 0.53  |  |
| F   | 0.040 | 0.070     | 1.02        | 1.78  |  |
| G   | 0.100 | 0.100 BSC |             | BSC   |  |
| Н   | 0.052 | 0.095     | 1.32        | 2.41  |  |
| J   | 0.008 | 0.015     | 0.20        | 0.38  |  |
| K   | 0.115 | 0.135     | 2.92        | 3.43  |  |
| L   | 0.300 | BSC       | 7.62 BSC    |       |  |
| М   | 0°    | 10°       | 0°          | 10°   |  |
| N   | 0.015 | 0.039     | 0.39        | 1.01  |  |

# **D SUFFIX**

PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE F

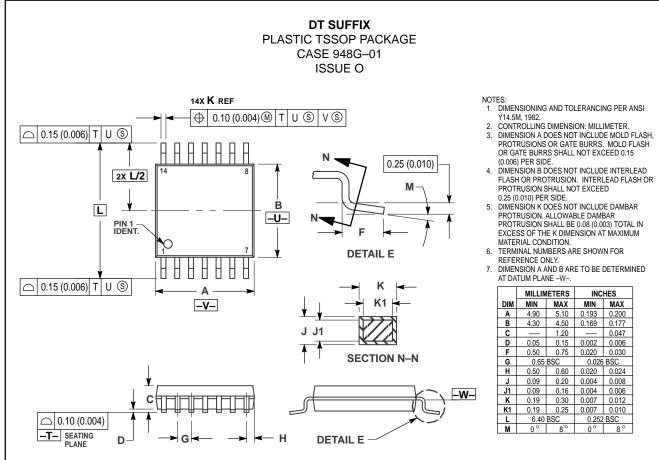
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- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DEP SIDE
- 4. MAXIMUM MOLLD PROTROSION 0.15 (0.000)
  PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR
  PROTRUSION, ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL
  IN EXCESS OF THE D DIMENSION AT
  MAXIMUM MATERIAL CONDITION.

|     | MILLIMETERS |      | INC   | HES   |
|-----|-------------|------|-------|-------|
| DIM | MIN         | MAX  | MIN   | MAX   |
| Α   | 8.55        | 8.75 | 0.337 | 0.344 |
| В   | 3.80        | 4.00 | 0.150 | 0.157 |
| С   | 1.35        | 1.75 | 0.054 | 0.068 |
| D   | 0.35        | 0.49 | 0.014 | 0.019 |
| F   | 0.40        | 1.25 | 0.016 | 0.049 |
| G   | 1.27        | BSC  | 0.050 | BSC   |
| J   | 0.19        | 0.25 | 0.008 | 0.009 |
| K   | 0.10        | 0.25 | 0.004 | 0.009 |
| M   | 0°          | 7°   | 0°    | 7°    |
| Р   | 5.80        | 6.20 | 0.228 | 0.244 |
| R   | 0.25        | 0.50 | 0.010 | 0.019 |

# **OUTLINE DIMENSIONS**



- MATERIAL CONDITION.
  TERMINAL NUMBERS ARE SHOWN FOR
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
   DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

|     | MILLIN | METERS | INCHES    |       |  |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN    | MAX    | MIN       | MAX   |  |
| Α   | 4.90   | 5.10   | 0.193     | 0.200 |  |
| В   | 4.30   | 4.50   | 0.169     | 0.177 |  |
| С   |        | 1.20   |           | 0.047 |  |
| D   | 0.05   | 0.15   | 0.002     | 0.006 |  |
| F   | 0.50   | 0.75   | 0.020     | 0.030 |  |
| G   | 0.65   | BSC    | 0.026     | BSC   |  |
| Н   | 0.50   | 0.60   | 0.020     | 0.024 |  |
| J   | 0.09   | 0.20   | 0.004     | 0.008 |  |
| J1  | 0.09   | 0.16   | 0.004     | 0.006 |  |
| K   | 0.19   | 0.30   | 0.007     | 0.012 |  |
| K1  | 0.19   | 0.25   | 0.007     | 0.010 |  |
| L   | 6.40   |        | 0.252 BSC |       |  |
| М   | ٥°     | 80     | n٥        | 80    |  |

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